



# Silicon carbide CoolSiC™ Schottky diodes

Selection guide

[www.infineon.com/sic](http://www.infineon.com/sic)



# Silicon carbide

## Improve efficiency and solution costs

Silicon carbide (SiC) devices belong to the so-called wide bandgap semiconductor group, which offers a number of attractive characteristics for high voltage power semiconductors when compared to commonly used silicon (Si). In particular, the much higher breakdown field strength and thermal conductivity of silicon carbide allow developing devices which by far outperform the corresponding silicon-based ones, and enable efficiency levels unattainable otherwise. Infineon's portfolio of SiC devices covers 600 V and 650 V to 1200 V Schottky diodes as well as the revolutionary CoolSiC™ MOSFET.

## Advantages of silicon carbide over silicon devices

The differences in material properties between silicon carbide and silicon limit the fabrication of practical silicon unipolar diodes (Schottky diodes) to a range up to 100-150 V, with a relatively high on-state resistance and leakage current. In SiC, Schottky diodes can reach a much higher breakdown voltage. Infineon is the world's first SiC discrete power supplier. Infineon offers products up to 1200 V in discrete packages and up to 1700 V in modules.

### Features

- › No reverse-recovery charge
- › Purely capacitive switching
- › High operating temperature  
( $T_{j, max} = 175^{\circ}\text{C}$ )

### Benefits

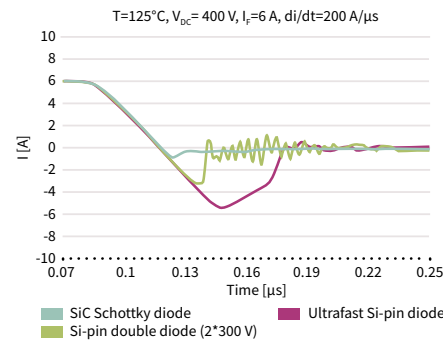
- › System efficiency improvement compared to Si-based diodes
- › Reduced cooling requirements
- › Enabling higher frequency/increased power density
- › Higher system reliability due to lower operating temperature
- › Reduced EMI

### Advantages

- › Low turn-off losses
- › Reduction of CoolMOS™ SJ MOSFET or IGBT turn-on loss
- › Switching losses independent from load current, switching speed and temperature

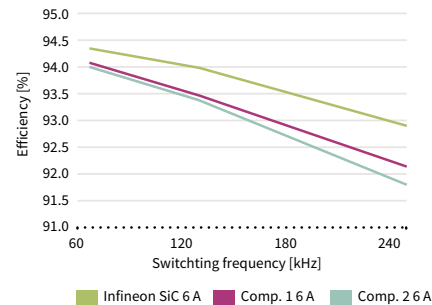
### Applications

- › Server power
- › Telecom power supply
- › Solar
- › UPS
- › EV charging
- › Energy storage
- › PC power supply
- › Motor drives
- › Lighting
- › CAV
- › Industrial welding



### Reverse-recovery charge of SiC Schottky diodes versus Si-pin diodes

The majority of carrier characteristics imply no reverse-recovery charge and the only contribution to the switching losses comes from the tiny displacement charge of capacitive nature. In the same voltage range, silicon devices have a bipolar component resulting in much higher switching losses. The graph shows the comparison between various 600 V devices.



### Improved system efficiency (PFC in CCM mode operation, full load, low line)

The fast switching characteristics of the SiC diodes provide clear efficiency improvements at system level. The performance gap between SiC and high-end silicon devices increases with the operating frequency.

Infineon is the world's first SiC discrete power supplier. The long market presence and experience enable Infineon to deliver highly reliable, industry-leading SiC performance. With over 10 years pioneering experience in developing and manufacturing SiC diodes, Infineon's latest CoolSiC™ Schottky diode generation 6 family sets benchmark in quality, efficiency and reliability.

## Silicon carbide portfolio

## CoolSiC™ Schottky diodes 650 V G6

ACTIVE &amp; PREFERRED



$I_F$ [A]	TO-220 R2L	Double DPAK
4	IDH04G65C6	IDDD04G65C6
6	IDH06G65C6	IDDD06G65C6
8	IDH08G65C6	IDDD08G65C6
10	IDH10G65C6	IDDD10G65C6
12	IDH12G65C6	IDDD12G65C6 *
16	IDH16G65C6	IDDD16G65C6
20	IDH20G65C6	IDDD20G65C6

\*For more information on the product, contact our product support

## CoolSiC™ Schottky diodes 600 V G3

ACTIVE



$I_F$ [A]	TO-220 R2L	DPAK R2L
3	IDH03SG60C	IDD03SG60C
4	IDH04SG60C	IDD04SG60C
5	IDH05SG60C	IDD05SG60C
6	IDH06SG60C	IDD06SG60C
8	IDH08SG60C	IDD08SG60C
9	IDH09SG60C	IDD09SG60C
10	IDH10SG60C	IDD10SG60C
12	IDH12SG60C	IDD12SG60C *

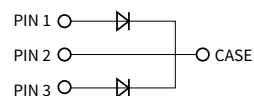
\*For more information on the product, contact our product support

## CoolSiC™ Schottky diodes 650 V G5

ACTIVE



$I_F$ [A]	TO-220 R2L	TO-247 Dual Die	TO-247	D <sup>2</sup> PAK R2L	ThinPAK 8x8
2	IDH02G65C5			IDK02G65C5	IDL02G65C5
3	IDH03G65C5			IDK03G65C5	
4	IDH04G65C5			IDK04G65C5	IDL04G65C5
5	IDH05G65C5			IDK05G65C5	
6	IDH06G65C5			IDK06G65C5	IDL06G65C5
8	IDH08G65C5			IDK08G65C5	IDL08G65C5
9	IDH09G65C5			IDK09G65C5	
10	IDH10G65C5		IDW10G65C5	IDK10G65C5	IDL10G65C5
12	IDH12G65C5		IDW12G65C5	IDK12G65C5	IDL12G65C5
16	IDH16G65C5		IDW16G65C5		
20	IDH20G65C5	IDW20G65C5B	IDW20G65C5		
24		IDW24G65C5B			
30/32		IDW32G65C5B	IDW30G65C5		
40		IDW40G65C5B	IDW40G65C5		

„B” in product name refers to dual die  
with the common-cathode configuration.

## CoolSiC™ Schottky diodes 1200 V G5

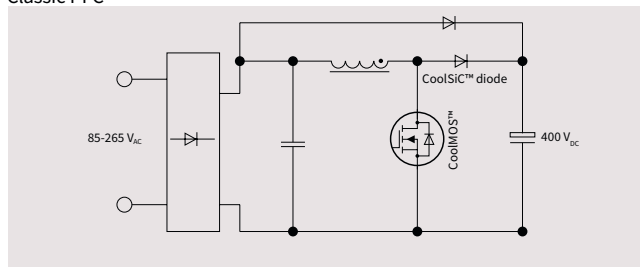
ACTIVE &amp; PREFERRED

$I_F$ [A]	TO-220 R2L	TO-247 Dual Die	TO-247 R2L	DPAK R2L	D <sup>2</sup> PAK R2L
2	IDH02G120C5			IDM02G120C5	IDK02G120C5
5	IDH05G120C5			IDM05G120C5	IDK05G120C5
8	IDH08G120C5			IDM08G120C5	IDK08G120C5
10	IDH10G120C5	IDW10G120C5B	IDWD10G120C5	IDM10G120C5	IDK10G120C5
15/16	IDH16G120C5	IDW15G120C5B	IDWD15G120C5		IDK16G120C5
20	IDH20G120C5	IDW20G120C5B	IDWD20G120C5		IDK20G120C5
30		IDW30G120C5B	IDWD30G120C5		
40		IDW40G120C5B	IDWD40G120C5		

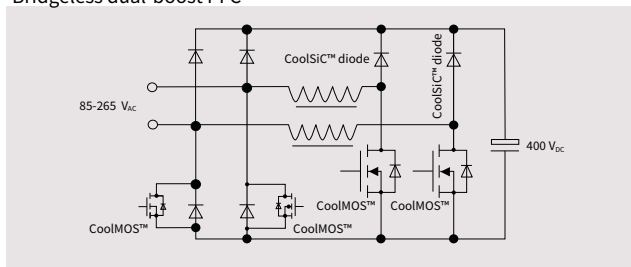
For more details on the product,  
click on the part number.

## Common SiC diodes applications and topologies

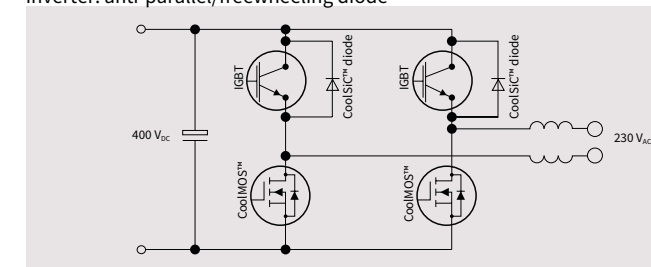
Classic PFC



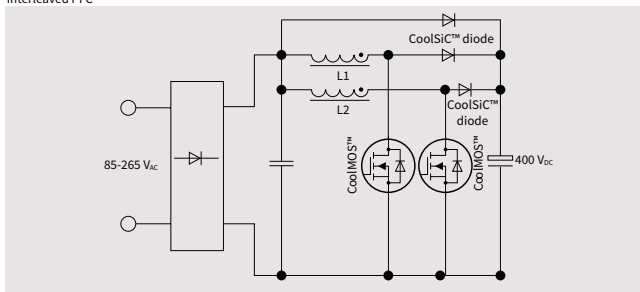
Bridgeless dual-boost PFC



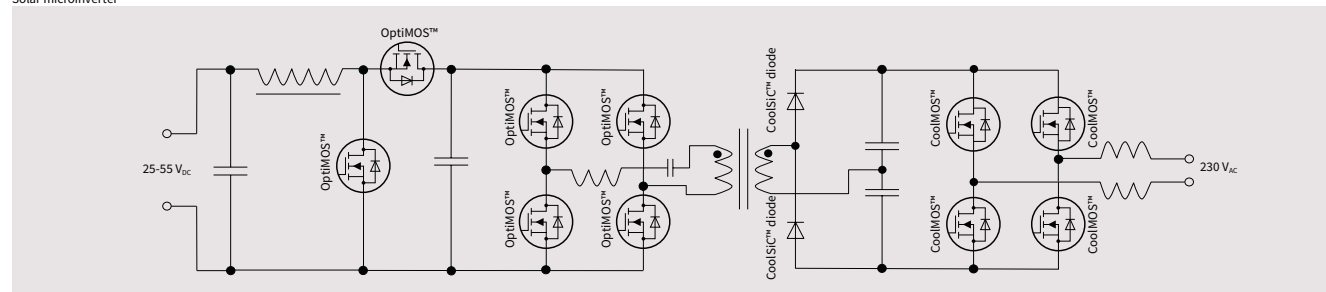
Inverter: anti-parallel/freewheeling diode



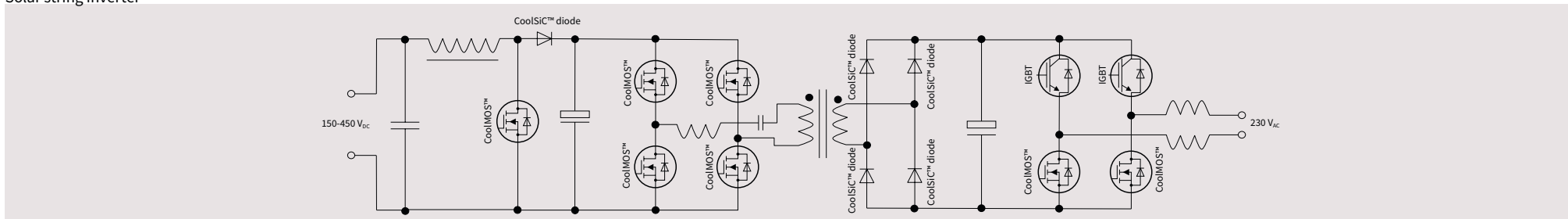
Interleaved PFC



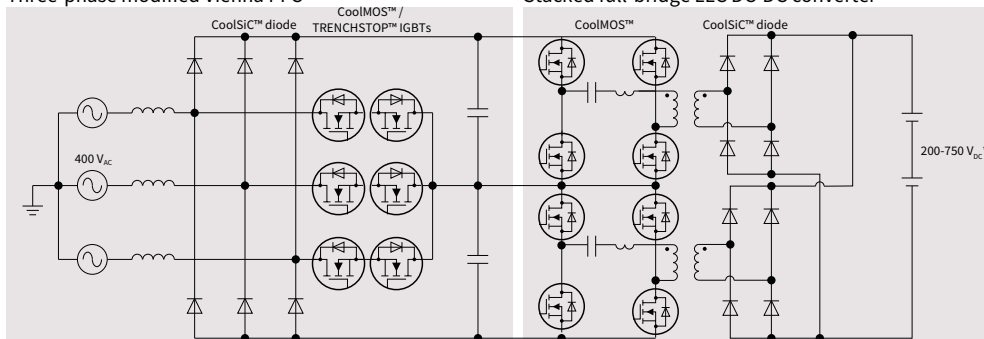
Solar microinverter



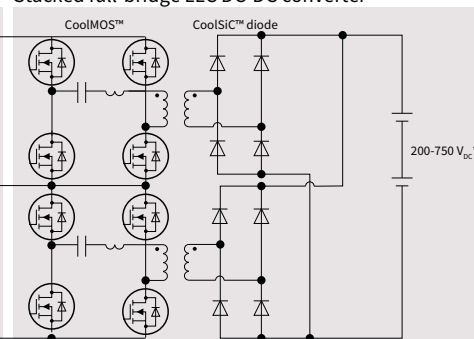
Solar string inverter



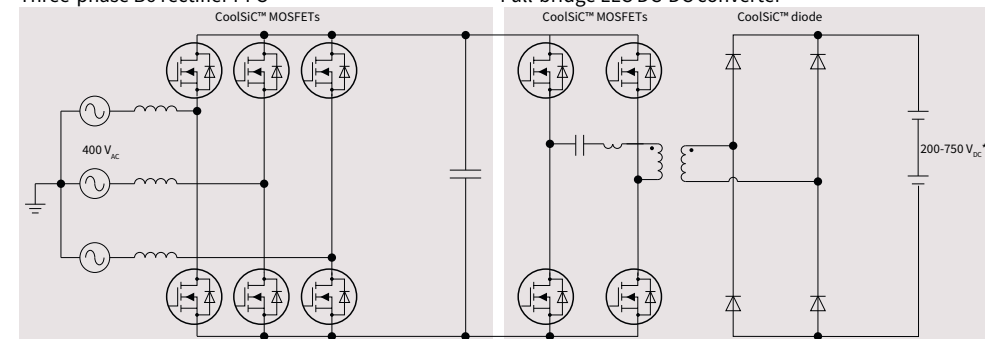
Three-phase modified Vienna PFC



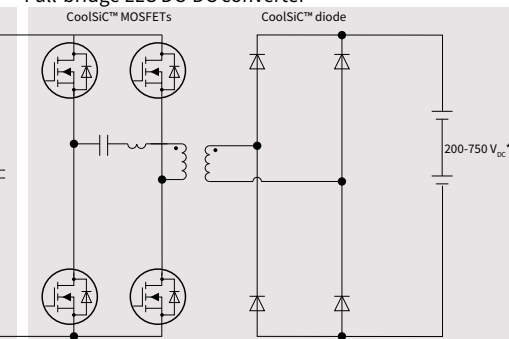
Stacked full-bridge LLC DC-DC converter



Three-phase B6 rectifier PFC



Full-bridge LLC DC-DC converter



## Where to buy

Infineon distribution partners and sales offices:  
[www.infineon.com/wheretobuy](http://www.infineon.com/wheretobuy)



Mobile product catalog  
Mobile app for iOS and Android.

## Service hotline

Infineon offers its toll-free 0800/4001 service hotline as one central number, available 24/7 in English, Mandarin and German.

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- › China, mainland ..... 4001 200 951 (Mandarin/English)
- › India ..... 000 800 4402 951 (English)
- › USA ..... 1-866 951 9519 (English/German)
- › Other countries ..... 00\* 800 951 951 951 (English/German)
- › Direct access ..... +49 89 234-0 (interconnection fee, German/English)

\* Please note: Some countries may require you to dial a code other than "00" to access this international number.  
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